

**TC74VHC238F, TC74VHC238FN, TC74VHC238FT****3 - TO - 8 LINE DECODER**

(Note) The JEDEC SOP (FN) is not available in Japan.

The TC74VHC238 is an advanced high speed CMOS 3 - to - 8 DECODER fabricated with silicon gate C<sup>2</sup>MOS technology.

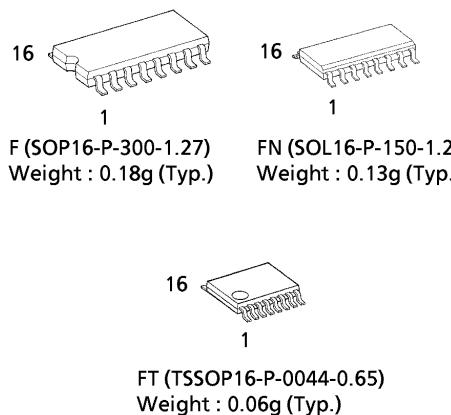
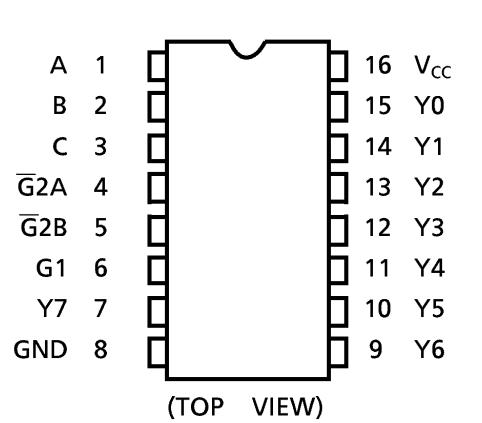
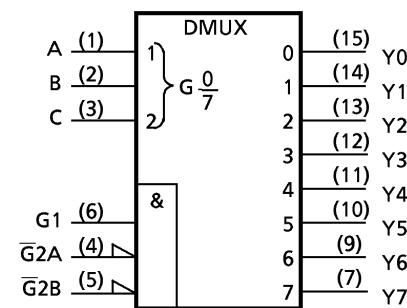
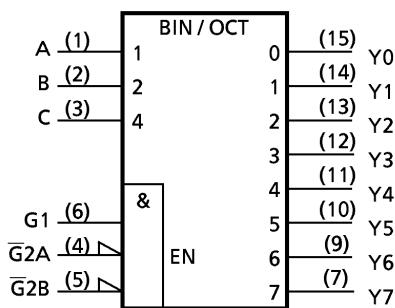
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs (Y0 - Y7) will go High.

When enable input G1 is held low or either  $\bar{G}2A$  or  $\bar{G}2B$  is held high, decoding function is inhibited and all outputs go Low.  $G1$ ,  $\bar{G}2A$ , and  $\bar{G}2B$  inputs are provided to ease cascade connection and for use as an address decoder for memory systems. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

**FEATURES :**

- High Speed..... $t_{pd} = 5.5\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{Max.})$  at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range....  $V_{CC} (\text{opr}) = 2\text{V} \sim 5.5\text{V}$
- Pin and Function Compatible with 74ALS238

**PIN ASSIGNMENT****IEC LOGIC SYMBOL**

961001EBA2

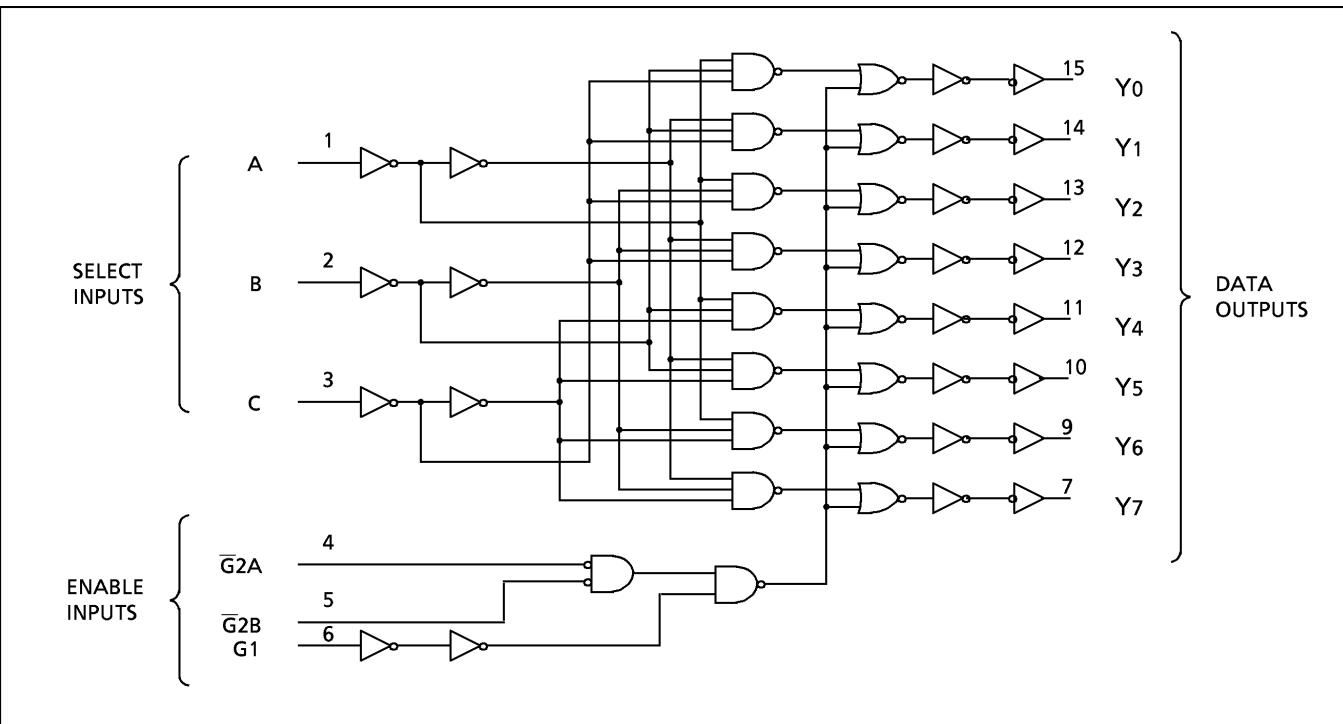
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## TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT			Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7	
G1	$\bar{G}2A$	$\bar{G}2B$	C	B	A									
L	X	X	X	X	X	L	L	L	L	L	L	L	L	NONE
X	H	X	X	X	X	L	L	L	L	L	L	L	L	NONE
X	X	H	X	X	X	L	L	L	L	L	L	L	L	NONE
H	L	L	L	L	L	H	L	L	L	L	L	L	L	Y0
H	L	L	L	L	H	L	H	L	L	L	L	L	L	Y1
H	L	L	L	H	L	L	L	H	L	L	L	L	L	Y2
H	L	L	L	H	H	L	L	L	H	L	L	L	L	Y3
H	L	L	H	L	L	L	L	L	L	H	L	L	L	Y4
H	L	L	H	L	H	L	L	L	L	L	H	L	L	Y5
H	L	L	H	H	H	L	L	L	L	L	L	H	L	Y6
H	L	L	H	H	H	L	L	L	L	L	L	L	H	Y7

X : Don't Care

## LOGIC DIAGRAM



961001EBA2'

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- The information contained herein is subject to change without notice.

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~7.0	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	-20	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 75$	mA
Power Dissipation	$P_D$	180	mW
Storage Temperature	$T_{STG}$	-65~150	°C

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	$V_{IN}$	0~5.5	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$dt/dv$	0~100 ( $V_{CC} = 3.3 \pm 0.3$ V) 0~20 ( $V_{CC} = 5 \pm 0.5$ V)	ns/V

## DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	$V_{IH}$		2.0 3.0~ 5.5	1.50 $V_{CC} \times 0.7$	—	—	1.50 $V_{CC} \times 0.7$	—	V
Low - Level Input Voltage	$V_{IL}$		2.0 3.0~ 5.5	—	—	0.50 $V_{CC} \times 0.3$	—	0.50 $V_{CC} \times 0.3$	V
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	— —	— —	2.48 3.80	— —
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50\mu A$	2.0 3.0 4.5	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	— — —
			$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	— —	0.36 0.36	— —	0.44 0.44	— —
Input Leakage Current	$I_{IN}$	$V_{IN} = 5.5V$ or GND	0~5.5	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu A$
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	

AC ELECTRICAL CHARACTERISTICS (Input  $t_r = t_f = 3\text{ns}$ )

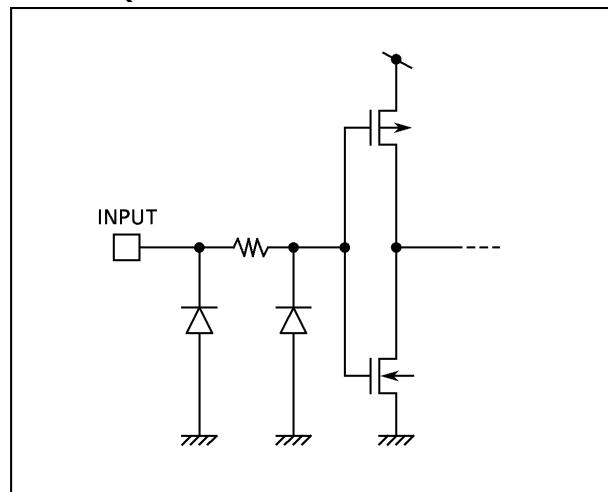
PARAMETER	SYMBOL	TEST CONDITION		$T_a = 25^\circ\text{C}$			$T_a = -40\sim85^\circ\text{C}$		UNIT	
		$V_{CC}(\text{V})$	$CL(\text{pF})$	MIN.	TYP.	MAX.	MIN.	MAX.		
Propagation Delay Time (A, B, C - Y)	$t_{pLH}$	$3.3 \pm 0.3$	15	—	8.0	12.3	1.0	14.5	ns	
			50	—	10.5	15.8	1.0	18.0		
			$5.0 \pm 0.5$	15	—	5.5	8.1	1.0	9.5	
			50	—	7.0	10.1	1.0	11.5		
	$t_{pHL}$	$3.3 \pm 0.3$	15	—	8.1	12.8	1.0	15.0		
			50	—	10.6	16.3	1.0	18.5		
			$5.0 \pm 0.5$	15	—	5.4	8.1	1.0	9.5	
			50	—	6.9	10.1	1.0	11.5		
Propagation Delay Time (G1 - Y)	$t_{pLH}$	$3.3 \pm 0.3$	15	—	8.1	12.3	1.0	14.5	ns	
			50	—	10.6	15.8	1.0	18.0		
			$5.0 \pm 0.5$	15	—	5.7	8.1	1.0	9.5	
			50	—	7.2	10.1	1.0	11.5		
Input Capacitance	$C_{IN}$				—	4	10	—	10	pF
Power Dissipation Capacitance	$C_{PD}$	(Note 1)			—	37	—	—	—	

Note (1)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

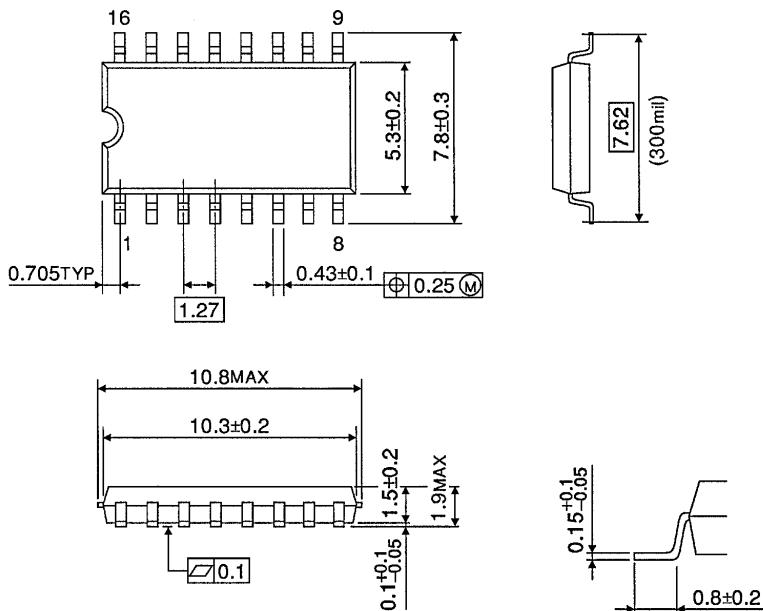
$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## INPUT EQUIVALENT CIRCUIT



## SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16-P-300-1.27)

Unit in mm

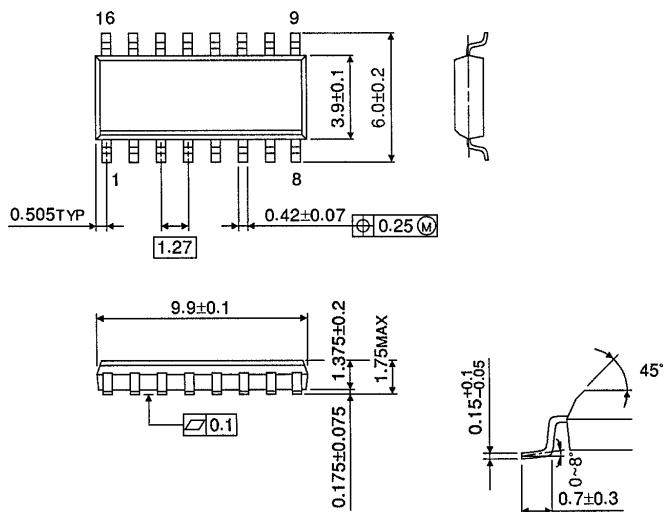


Weight : 0.18g (Typ.)

## SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16-P-150-1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.13g (Typ.)

## TSSOP 16PIN OUTLINE DRAWING (TSSOP16-P-0044-0.65)

Unit in mm

